

Replaces March 1998 version, DS4145-3.4

#### **APPLICATIONS**

- Induction Heating
- A.C. Motor Drives
- Inverters And Choppers
- Welding
- High Frequency Rectification
- UPS

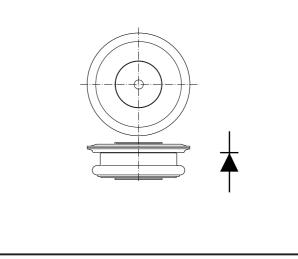
#### **FEATURES**

- Double Side Cooling
- High Surge Capability
- Low Recovery Charge

#### **VOLTAGE RATINGS**

Repetitive Peak Reverse Voltage V <sub>RRM</sub> V	Conditions
2500	$V_{RSM} = V_{RRM} + 100V$
2400	
2200	
2000	
	Reverse Voltage V <sub>RRM</sub> 2500 2400 2200

# cation



Outline type code: M771. See Package Detials for further information.

#### **CURRENT RATINGS**

Symbol	Parameter	Conditions		Units				
Double Sid	Double Side Cooled							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, $T_{case} = 65^{\circ}C$		А				
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 65^{\circ}C$	575	А				
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 65°C	525	А				
Single Side	Single Side Cooled (Anode side)							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, $T_{case} = 65^{\circ}C$		А				
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 65^{\circ}C$		А				
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 65°C	335	А				

# **DFS454**

## **Fast Recovery Diode**

DS4145-4.0 January 2000
-------------------------

# KEY PARAMETERS

V RRM	25007
F(AV)	365A
I <sub>FSM</sub>	3500A
Q	<b>200</b> μC
t <sub>rr</sub>	<b>2.0</b> μs

## **DFS454**

#### SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10 me holf size: with $0%$ // T = 150%	3.5	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	- 10ms half sine; with 0% $V_{RRM}$ , $T_j = 150^{\circ}C$	61 x 10 <sup>3</sup>	A <sup>2</sup> s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	40 me holf since with $E00/1/$ T $4E00$	2.8	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	- 10ms half sine; with 50% $V_{RRM}$ , $T_j = 150^{\circ}C$	39.2 x 10 <sup>3</sup>	A <sup>2</sup> s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10 me holf since with $100%$ // T $150%$	-	kA
l²t	I <sup>2</sup> t for fusing	- 10ms half sine; with 100% $V_{RRM}$ , $T_j = 150^{\circ}C$	-	A²s

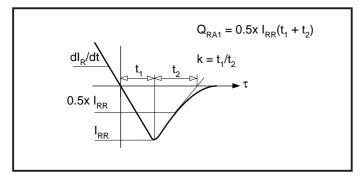
## THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
		Double side cooled	dc	-	0.07	°C/W
R <sub>th(j-c)</sub>	Thermal resistance - junction to case	Single side cooled	Anode dc	-	0.133	°C/W
			Cathode dc	-	0.147	°C/W
	R <sub>th(c-h)</sub> Thermal resistance - case to heatsink Clamping force 3.5kN with mounting compound	Clamping force 3.5kN	Double side	-	0.02	°C/W
R <sub>th(c-h)</sub>			Single side	-	0.04	°C/W
T <sub>vj</sub>	Virtual junction temperature	On-state (conducting)		-	150	°C
T <sub>stg</sub>	Storage temperature range			-55	175	°C
-	Clamping force			3.0	4.0	kN

## CHARACTERISTICS

Symbol	Parameter	Conditions	Тур.	Max.	Units
$V_{FM}$	Forward voltage	At 1000A peak, T <sub>case</sub> = 25°C	-	3.1	V
I <sub>RRM</sub>	Peak reverse current	At $V_{\text{RRM}}$ , $T_{\text{case}} = 150^{\circ}\text{C}$	-	50	mA
t <sub>rr</sub>	Reverse recovery time		2.0	-	μs
Q <sub>RA1</sub>	Recovered charge (50% chord)	I <sub>F</sub> = 750A, di <sub>RR</sub> /dt = 100A/μs	-	200	μC
I <sub>RM</sub>	Reverse recovery current	T <sub>case</sub> = 125°C, V <sub>R</sub> = 100V	150	-	А
К	Soft factor		1.3	-	-
V <sub>TO</sub>	Threshold voltage	At $T_{vj} = 150^{\circ}C$	-	1.64	V
r <sub>T</sub>	Slope resistance	At $T_{vj} = 150^{\circ}C$	-	1.54	mΩ
$V_{FRM}$	Forward recovery voltage	di/dt = 1000A/µs, T <sub>j</sub> = 125°C	-	120	V

# DEFINITION OF K FACTOR AND $\mathbf{Q}_{\text{RA1}}$



#### CURVES

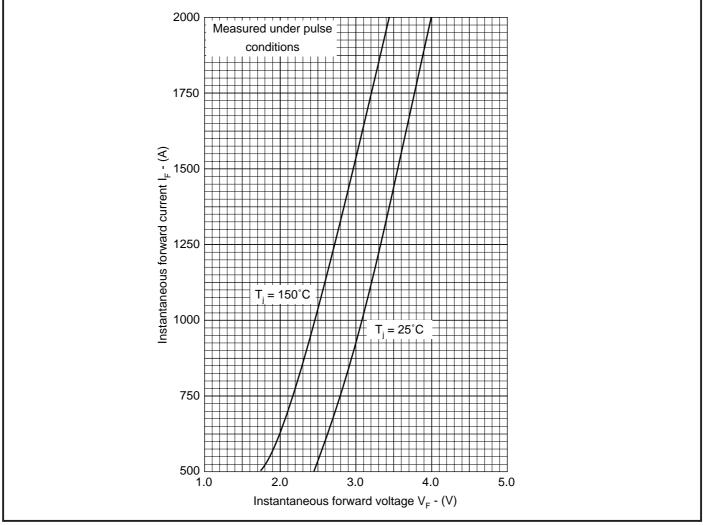


Fig. 1 Maximum (limit) forward characteristics

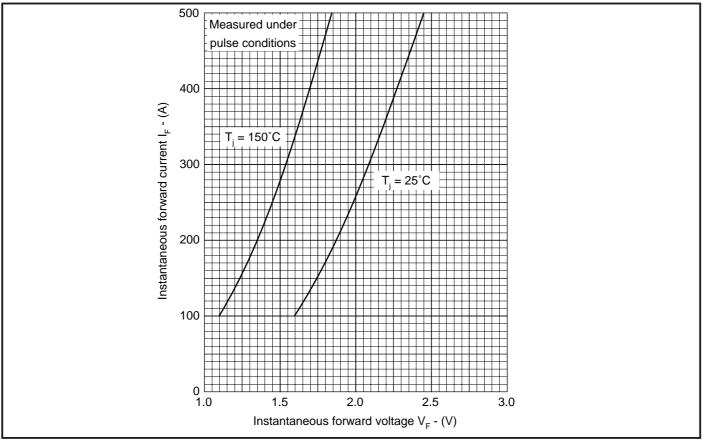
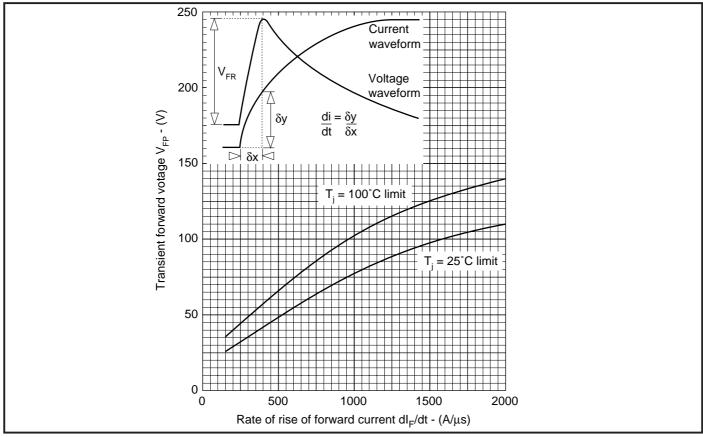
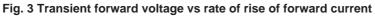
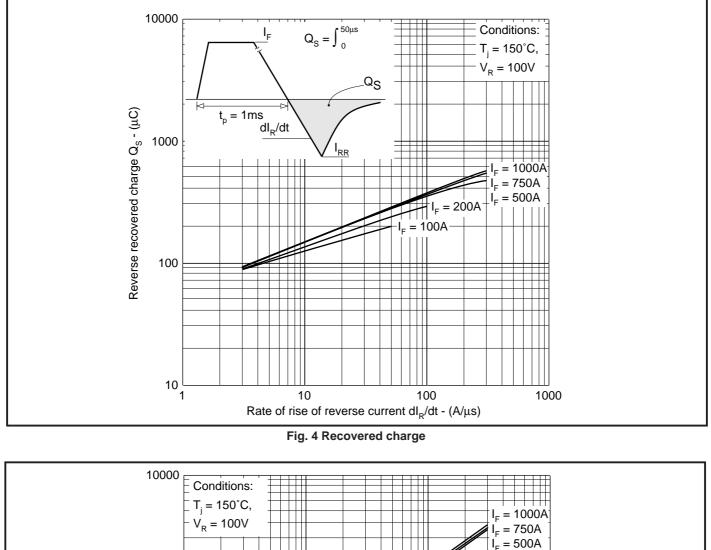


Fig. 2 Maximum (limit) forward characteristics





#### **DFS454**



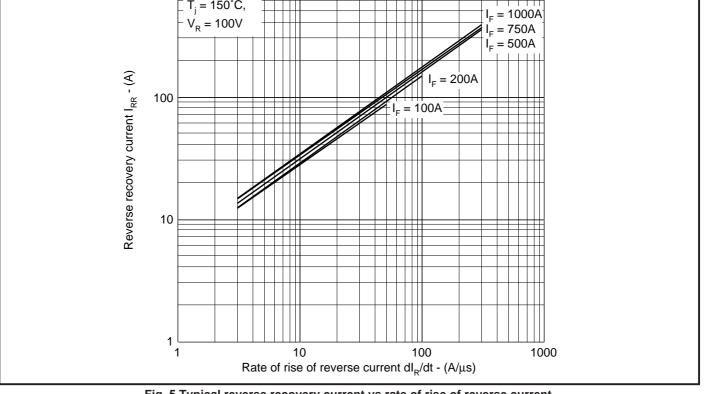


Fig. 5 Typical reverse recovery current vs rate of rise of reverse current

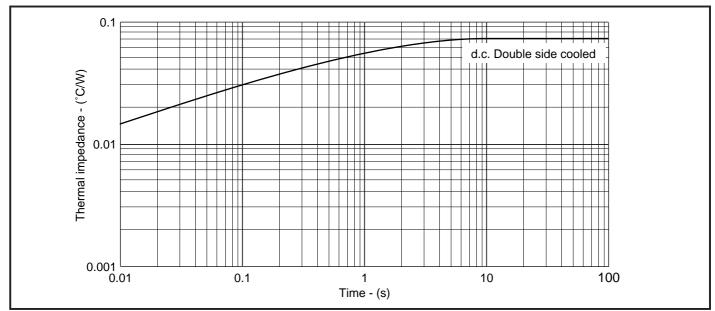
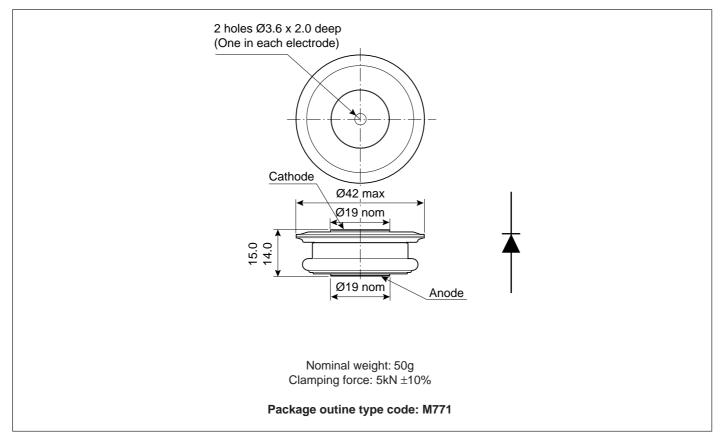


Fig. 6 Maximum (limit) transient thermal impedance - junction to case - (°C/W)

#### **PACKAGE DETAILS**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



#### ASSOCIATED PUBLICATIONS

Title	Application Note	
	Number	
Calculating the junction temperature or power semiconductors	AN4506	
Recommendations for clamping power semiconductors	AN4839	
Thyristor and diode measurement with a multi-meter	AN4853	
Use of $V_{TO}$ , $r_{T}$ on-state characteristic	AN5001	

#### POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink / clamping systems in line with advances in device types and the voltage and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the up to date CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete solution (PACs).

#### **DEVICE CLAMPS**

Disc devices require the correct clamping force to ensure their safe operation. The PACs range offers a varied selection of preloaded clamps to suit all of our manufactured devices. This include cube clamps for single side cooling of 'T' 22mm

Clamps are available for single or double side cooling, with high insulation versions for high voltage assemblies.

Please refer to our application note on device clamping, AN4839

#### HEATSINKS

Power Assembly has it's own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance or our semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest Sales Representative or the factory.



#### HEADQUARTERS OPERATIONS DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln. Lincolnshire. LN6 3LF. United Kingdom. Tel: 00-44-(0)1522-500500 Fax: 00-44-(0)1522-500550

#### DYNEX POWER INC.

Unit 7 - 58 Antares Drive, Nepean, Ontario, Canada K2E 7W6. Tel: 613.723.7035 Fax: 613.723.1518 Toll Free: 1.888.33.DYNEX (39639) http://www.dynexsemi.com

#### e-mail: power\_solutions@dynexsemi.com

CUSTOMER SERVICE CENTRES France, Benelux, Italy and Spain Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50 North America Tel: 011-800-5554-5554. Fax: 011-800-5444-5444 UK, Germany, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020 SALES OFFICES France, Benelux, Italy and Spain Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50 Germany Tel: 07351 827723 North America Tel: (613) 723-7035. Fax: (613) 723-1518. Toll Free: 1.888.33.DYNEX (39639) / Tel: (831) 440-1988. Fax: (831) 440-1989 / Tel: (949) 733-3005. Fax: (949) 733-2986. UK, Germany, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500200

These offices are supported by Representatives and Distributors in many countries world-wide. © Dynex Semiconductor 2000 Publication No. DS4145-4 Issue No. 4.0 January 2000 TECHNICAL DOCUMENTATION – NOT FOR RESALE. PRINTED IN UNITED KINGDOM

#### **Datasheet Annotations:**

Dynex Semiconductor annotate datasheets in the top right hard corner of the front page, to indicate product status. The annotations are as follows:-

Target Information: This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started.

Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

Advance Information: The product design is complete and final characterisation for volume production is well in hand.

No Annotation: The product parameters are fixed and the product is available to datasheet specification.

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or price of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available on request.

All brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.